

ROHS

HALOGEN FREE

Hyperfast Rectifier, 30 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES





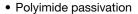
PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V_{R}	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	26 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature



 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

operate with MOSFETs or high speed IGBTs.

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals**: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 105 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	210	Α			
Repetitive peak forward current	I _{FRM}	$T_C = 105 ^{\circ}C, D = 0.50, f = 20 \text{kHz}$	60				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	-	-		
Forward voltage	V	I _F = 30 A	-	2.6	3.15	0	
	V _F	I _F = 30 A, T _J = 125 °C	-	2.1	-		
D	I _R	V _R = V _R rated	-	-	50		
Reverse leakage current		$T_J = 125$ °C, $V_R = V_R$ rated		-	500	μA	
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 100$) A/μs, V _R = 30 V	-	26	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns
		T _J = 125 °C		-	150	-	
Dook roopyony ourrent		T _J = 25 °C	$I_F = 20 \text{ A}$	-	12	-	Α
Peak recovery current	I _{RRM}	T _J = 125 °C	$dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	22	-	
Doverno recovery charge	0	T _J = 25 °C		-	530	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1550	-	
Deviana reservant times		T _J = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 800 \text{ V}$	-	80	-	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	120	-	
Dools recovery comment		T _J = 25 °C		-	22	-	A
Peak recovery current	I _{RRM}	T _J = 125 °C		-	37	-	
Reverse recovery charge	0	T _J = 25 °C		-	900	-	nC
	Q _{rr}	T _J = 125 °C		-	2300		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R_{thJC}		-	-	0.8	°C/W		
Weight			-	5.5	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style: TO-247AD 2L	E5PX3012L					

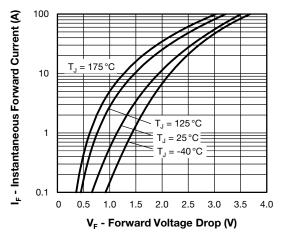


Fig. 1 - Typical Forward Voltage Drop Characteristics

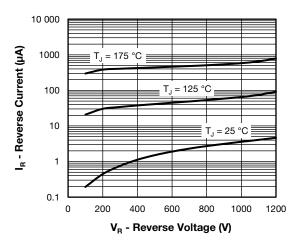


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

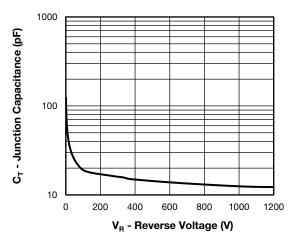


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

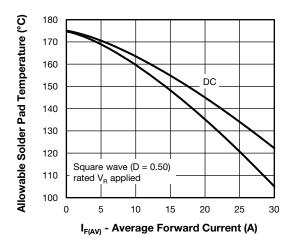


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

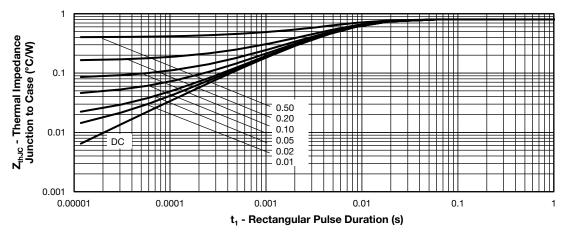


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

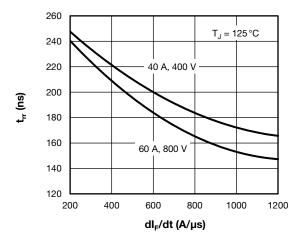


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

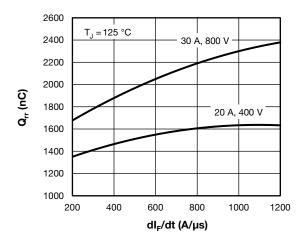


Fig. 7 - Typical Stored Charge vs. dl_F/dt

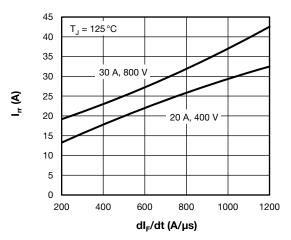


Fig. 8 - Typical Recovery Current vs. dl_F/dt

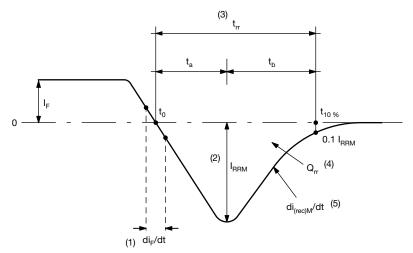


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\,$ Q_{rr} area under curve defined by t_0 and $t_{10}\,\%$

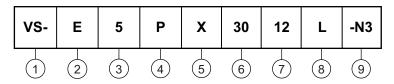
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $$t_0$$ (5) $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



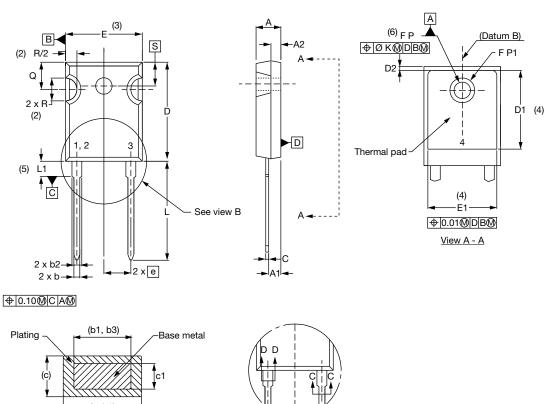
- 1 Vishay Semiconductors product
- 2 E = single diode
- 3 5 = Fred generation 5
- 4 Package: P = TO-247 package
- 5 X = hyperfast recovery
- Current rating (30 = 30 A)
- 7 Voltage rating (12 = 1200 V)
- Package: L = long lead (TO-247AD)
- 9 Environmental digit:
 - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PX3012L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				
Spice model	www.vishay.com/doc?96684				

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	254	0.0	10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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